# Design of a Simple CS Amplifier

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#### I. CS AMPLIFIER

The desired specs are as follows:

- $|A_v| > 40$  at  $V_{DS} = V_{DD}/2 = 0.9V$
- Output swing: 400mV
- Unity-gain frequency:  $f_u = 100MHz$ ,  $C_L = 5pF$
- $V^* = 200mV$

#### A. Selecting $I_D$

The transconductance can be obtained from:

$$g_m = 2\pi f_u C_L$$

this gives us

$$g_m = 3.14 \ mS$$

The current can be obtained from:

$$V^* = 2 \cdot \left(\frac{g_m}{I_D}\right)^{-1}$$

and a  $V^{*}$  of  $200 \; mV$  corresponds to a  $g_m/I_D$  of 10.

Thus,

$$I_D = 314 \ \mu A$$

## B. Choosing the length

To find the appropriate length, I did a DC sweep on VGS and checked if the intrinsic gain at  $V^*$  is > 40.

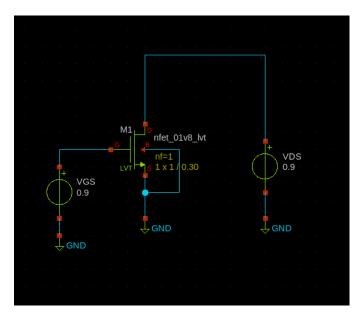


Fig. 1. Schematic diagram

At the minimum length, the intrinsic gain is lower than what is desired. We select  $L=0.30\mu m$  since it satisfies the specifications.  $L=0.25\mu m$  also meets the specifications. However, for a greater swing, the larger length is selected.

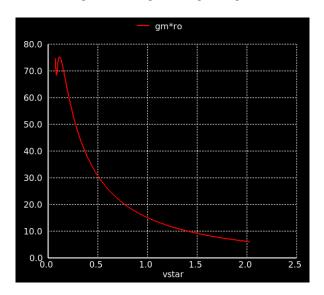


Fig. 2. Intrinsic gain

The  $V^*$  vs  $I_D$  plot for a transistor with  $W=1\mu m, L=0.30\mu m$  is shown below.

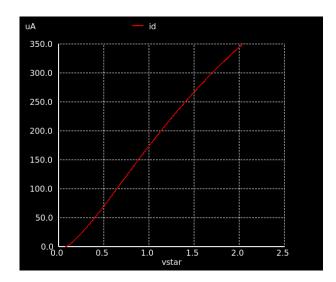


Fig. 3.  $I_D$  vs  $V^*$ ,  $W = 1\mu m$ 

#### C. Scaling the width

A python script is used to calculate the scale factor  $k_W$  that meets the required  $I_D$ . The width is scaled using  $k_W$ . Multiplying the width by  $k_W$  scales  $I_D$  by approximately the same factor. For this activity,  $k_W=21$ . To check, a MEAS directive is used. The required current is  $I_D=314\mu A$ , what we got is  $I_D=345\mu A$ , which is quite close.

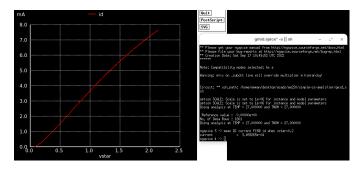


Fig. 4.  $I_D$  vs  $V^*$ ,  $W = 21 \mu m$ 

## D. Output and input swing

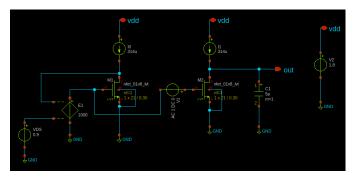


Fig. 5. Schematic

To get the input and output swing, we use the schematic in Fig. 5. Since  $V_{GS}$  is a function of  $V_{DS}$ , we can plot  $a_o$  vs  $V_{DS}$  to get the maximum output swing and  $a_o$  vs  $V_{GS}$  to get the corresponding input swing.

# 1) Output Swing: at $V_{DS} \approx 0.52$ , $a_o \geq 40$ .

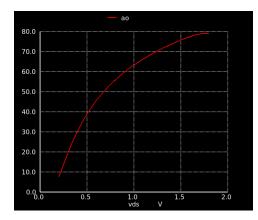


Fig. 6.  $a_o$  vs  $V_{DS}$ 

## 2) Input Swing: at $V_{GS} \approx 0.71$ , $a_o \ge 40$ .

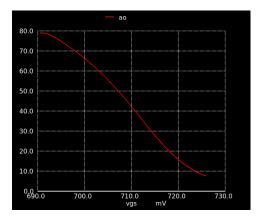


Fig. 7.  $a_o$  vs  $V_{GS}$ 

Thus, the maximum symmetric output voltage is  $0.52 \le V_{DS} \le 1.48$  for a total swing of 0.96V. The corresponding input is  $0.695 \le V_{GS} \le 0.71$  with a 15mV swing.

#### E. AC analysis

Using Fig. 5, an AC sweep from 1Hz to 1GHz is used to obtain Fig. 8. Using a MEAS directive,  $f_u=104MHz$  which is close to our desired  $f_u$ . At low frequencies, the gain is  $\approx 35dB$  which is  $\approx 60~V/V$ 

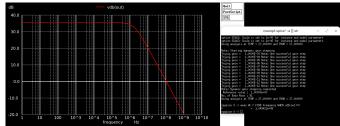


Fig. 8. Magnitude response

# F. Discussions

These are my expected results. Since some values are estimated, there are slight deviations with the desired specifications.

## II. CS Amplifier with High $f_t$

To get a high  $f_t$ , we need a high  $I_D$  and small L. Decreasing L increases  $f_t$  if  $I_D$  is kept constant. However, since there are no constraints on area and how high  $I_D$  could be, the limit would be related to the maximum W that can be used on the PDK.

## A. Selecting the width

For this PDK, the highest width that can be used is  $W = 99.9\mu m$ . We use this value to get the maximum  $I_D$ .

## B. Choosing the length and $V^*$

Ideally to get the highest  $f_t$ , we should select the minimum length. However, the minimum length does not have sufficient intrinsic gain. We use Fig. 1 to determine the appropriate length and  $V^*$ . Since the load is an ideal current source, the gain is only limited by the lower bound  $\approx 700mV$ . We use  $V_{DS}=0.7V$  for the simulation.

1)  $a_o$  vs  $V^*$ : For  $0.20\mu m \le L \le 0.25\mu m$ , the  $a_o$  vs  $V^*$  plot is shown below.

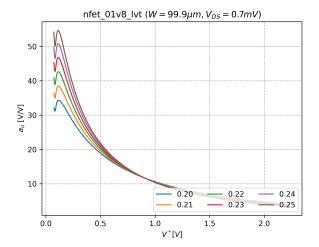


Fig. 9. Intrinsic gain

Since we need  $a_o > 40$ , only lengths  $\geq 0.22 \mu m$  can be used.

2)  $f_t vs V^*$ : To trim down the possible options, we use the plot below.

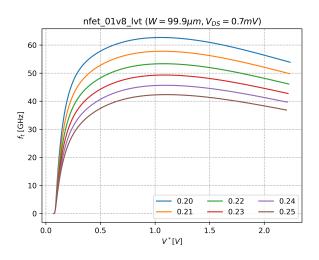


Fig. 10. Transition frequency

Considering the two plots, we choose  $V^* = 0.19V$  and  $L = 0.23 \mu m$  since it has the highest  $f_t$ . The gain and swing

at these values are also within the required specifications. The obtained  $f_t$  is 28GHz.

## C. Obtaining $g_m$ and $f_u$

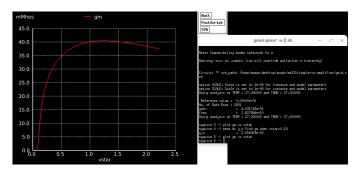


Fig. 11.  $g_m$  vs  $V^*$ 

From Fig. 11,  $g_m=20.54mS$  at  $V^*=0.19V$ . The target unity-gain frequency is:

$$f_u = \frac{g_m}{2\pi C_L} = 653.81MHz$$

with  $I_D = 1.95 mA$ .

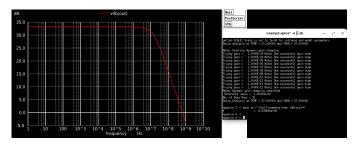


Fig. 12. Unity-gain frequency

Looking at Fig. 12,  $f_u \approx 654MHz$ . The desired  $f_u$  is met.

#### D. Output and input swing

1) Output Swing: From the plot below, we can see that  $a_o=40.32$  at  $V_{DS}=0.7$ . At  $V_{DS}=1.1,\ a_o\approx 50$ .

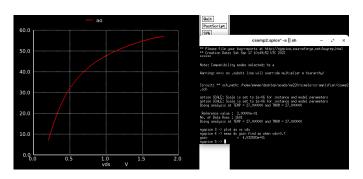


Fig. 13.  $a_o$  vs  $V_{DS}$ 

2) Input Swing: Sweeping  $V_{DS}$  from 700mV to 1.1V, we get the following  $a_o$  vs  $V_{GS}$  plot. The input  $V_{GS}$  that produces  $700mV \leq V_{DS} \leq 1.1V$  ranges from 719mV to 727mV. The maximum swing is 8mV.

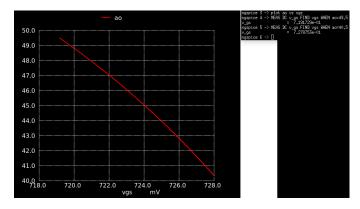


Fig. 14.  $a_o$  vs  $V_{GS}$ 

#### E. Discussions

First, the choice of  $V^*$  depends on both gain and desired  $f_t$ . If we increase  $V^*$ , we can get a higher  $f_t$  but the gain will decrease. To maximize  $f_t$ , The maximum  $V^*$  that satisfies both gain and swing should be chosen. This amplifier is designed to have an approximate output swing of  $\pm 200mV$  with a DC level of 0.9V because of  $f_t$  constraints.

The first design has  $I_D=314\mu A$ . For this design,  $I_D=1.95mA$ . The  $I_D$  is more than 6 times higher. RF applications would benefit from a high  $f_u$  but this might not be usable at all because of very high current consumption.